Programmable Timer

The MC14541B programmable timer consists of a 16–stage binary counter, an integrated oscillator for use with an external capacitor and two resistors, an automatic power–on reset circuit, and output control logic.

Timing is initialized by turning on power, whereupon the power–on reset is enabled and initializes the counter, within the specified V_{DD} range. With the power already on, an external reset pulse can be applied. Upon release of the initial reset command, the oscillator will oscillate with a frequency determined by the external RC network. The 16–stage counter divides the oscillator frequency (f_{osc}) with the nth stage frequency being $f_{osc}/2^n$.

- Available Outputs 2⁸, 2¹⁰, 2¹³ or 2¹⁶
- Increments on Positive Edge Clock Transitions
- Built–in Low Power RC Oscillator (± 2% accuracy over temperature range and ± 20% supply and ± 3% over processing at < 10 kHz)
- Oscillator May Be Bypassed if External Clock Is Available (Apply external clock to Pin 3)
- External Master Reset Totally Independent of Automatic Reset Operation
- Operates as 2ⁿ Frequency Divider or Single Transition Timer
- Q/\overline{Q} Select Provides Output Logic Level Flexibility
- Reset (auto or master) Disables Oscillator During Resetting to Provide No Active Power Dissipation
- Clock Conditioning Circuit Permits Operation with Very Slow Clock Rise and Fall Times
- Automatic Reset Initializes All Counters On Power Up
- Supply Voltage Range = 3.0 Vdc to 18 Vdc with Auto Reset Disabled (Pin $5 = V_{DD}$)
 - = 8.5 Vdc to 18 Vdc with Auto Reset Enabled (Pin 5 = V_{SS})

Symbol	Parameter	Value	Unit
- oyinisoi		Tuluo	-
V _{DD}	DC Supply Voltage Range	-0.5 to +18.0	V
V _{in} , V _{out}	Input or Output Voltage Range (DC or Transient)	-0.5 to V _{DD} + 0.5	V
l _{in}	Input Current (DC or Transient)	±10 (per Pin)	mA
I _{out}	Output Current (DC or Transient)	±45 (per Pin)	mA
P _D	Power Dissipation, per Package (Note 3.)	500	mW
T _A	Ambient Temperature Range	-55 to +125	°C
T _{stg}	Storage Temperature Range	-65 to +150	°C
TL	Lead Temperature (8–Second Soldering)	260	°C

MAXIMUM RATINGS (Voltages Referenced to V_{SS}) (Note 2.)

2. Maximum Ratings are those values beyond which damage to the device may occur.

3. Temperature Derating:

Plastic "P and D/DW" Packages: - 7.0 mW/°C From 65°C To 125°C

ON Semiconductor

http://onsemi.com

		MARKING
	PDIP–14 P SUFFIX CASE 646	DIAGRAMS
Careford and	SOIC-14 D SUFFIX CASE 751A	14000000 14541B 0 AWLYWW 10000000
- Anternet	TSSOP-14 DT SUFFIX CASE 948G	14 <u>8888888</u> 14 541B 6 ALYW 19999999
TUTTE	SOEIAJ–14 F SUFFIX CASE 965	14 MC14541B AWLYWW
A WL or L YY or Y WW or		ot

ORDERING INFORMATION

Device	Package	Shipping
MC14541BCP	PDIP-14	2000/Box
MC14541BD	SOIC-14	55/Rail
MC14541BDR2	SOIC-14	2500/Tape & Reel
MC14541BDT	TSSOP-14	96/Rail
MC14541BDTR2	TSSOP-14	2500/Tape & Reel
MC14541BF	SOEIAJ-14	See Note 1.
MC14541BFEL	SOEIAJ-14	See Note 1.

 For ordering information on the EIAJ version of the SOIC packages, please contact your local ON Semiconductor representative.

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}.$

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either $\rm V_{SS}$ or $\rm V_{DD}$). Unused outputs must be left open.

PIN ASSIGNMENT

R _{tc} [1•	14	l v _{dd}				
C _{tc}	2	13]в				
R _S [3	12	A				
NC [4	11] NC				
ar [5	10] MODE				
MR [6	9] Q/ <u>Q</u> SEL				
v _{ss} C	7	8	ο				
NC = NO CONNECTION							

ELECTRICAL	CHARACTERISTICS	(Voltages Referenced to V _{SS}))

			V _{DD}	- 5	5°C		25°C		125	S°C	
Characteristic		Symbol	Vdc	Min	Max	Min	Тур ^(4.)	Max	Min	Max	Unit
Output Voltage $V_{in} = V_{DD}$ or 0	"0" Level	V _{OL}	5.0 10 15	 	0.05 0.05 0.05	_ _ _	0 0 0	0.05 0.05 0.05	 	0.05 0.05 0.05	Vdc
$V_{in} = 0 \text{ or } V_{DD}$	"1" Level	V _{OH}	5.0 10 15	4.95 9.95 14.95		4.95 9.95 14.95	5.0 10 15		4.95 9.95 14.95		Vdc
Input Voltage $(V_O = 4.5 \text{ or } 0.5 \text{ Vdc})$ $(V_O = 9.0 \text{ or } 1.0 \text{ Vdc})$ $(V_O = 13.5 \text{ or } 1.5 \text{ Vdc})$	"0" Level	V _{IL}	5.0 10 15		1.5 3.0 4.0		2.25 4.50 6.75	1.5 3.0 4.0		1.5 3.0 4.0	Vdc
$\begin{array}{l} (V_{O} = 0.5 \text{ or } 4.5 \text{ Vdc}) \\ (V_{O} = 1.0 \text{ or } 9.0 \text{ Vdc}) \\ (V_{O} = 1.5 \text{ or } 13.5 \text{ Vdc}) \end{array}$	"1" Level	V _{IH}	5.0 10 15	3.5 7.0 11		3.5 7.0 11	2.75 5.50 8.25		3.5 7.0 11		Vdc
Output Drive Current $(V_{OH} = 2.5 \text{ Vdc})$ $(V_{OH} = 9.5 \text{ Vdc})$ $(V_{OH} = 13.5 \text{ Vdc})$	Source	I _{ОН}	5.0 10 15	- 7.96 - 4.19 - 16.3		- 6.42 - 3.38 - 13.2	- 12.83 - 6.75 - 26.33		- 4.49 - 2.37 - 9.24		mAdc
(V _{OL} = 0.4 Vdc) (V _{OL} = 0.5 Vdc) (V _{OL} = 1.5 Vdc)	Sink	I _{OL}	5.0 10 15	1.93 4.96 19.3		1.56 4.0 15.6	3.12 8.0 31.2		1.09 2.8 10.9		mAdc
Input Current		l _{in}	15	—	± 0.1	_	±0.00001	± 0.1	—	± 1.0	μAdc
Input Capacitance (V _{in} = 0)		C _{in}	—	-	—	-	5.0	7.5	-	—	pF
Quiescent Current (Pin 5 is High) Auto Reset Disabled		I _{DD}	5.0 10 15		5.0 10 20		0.005 0.010 0.015	5.0 10 20		150 300 600	μAdc
Auto Reset Quiescent Cur (Pin 5 is low)	rent	I _{DDR}	10 15	_	250 500	_	30 82	250 500	_	1500 2000	μAdc
Supply Current ^(5.) (6.) (Dynamic plus Quiesce	ent)	۱ _D	5.0 10 15			$I_{D} = (0)$).4 μA/kHz) f).8 μA/kHz) f 1.2 μA/kHz) f	+ I _{DD}			μAdc

4. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

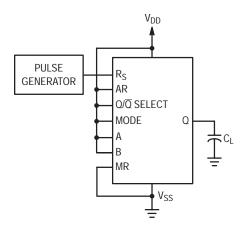
5. The formulas given are for the typical characteristics only at 25°C.

When using the on chip oscillator the total supply current (in μAdc) becomes: I_T = I_D + 2 C_{tc} V_{DD} f x 10⁻³ where I_D is in μA, C_{tc} is in pF, V_{DD} in Volts DC, and f in kHz. (see Fig. 3) Dissipation during power–on with automatic reset enabled is typically 50 μA @ V_{DD} = 10 Vdc.

SWITCHING CHARACTERISTICS (7.) (CL = 50 pF, TA = 25° C)

Characteristic	Symbol	V _{DD}	Min	Тур ^(8.)	Max	Unit
Output Rise and Fall Time t_{TLH} , $t_{THL} = (1.5 \text{ ns/pF}) C_L + 25 \text{ ns}$ t_{TLH} , $t_{THL} = (0.75 \text{ ns/pF}) C_L + 12.5 \text{ ns}$ t_{TLH} , $t_{THL} = (0.55 \text{ ns/pF}) C_L + 9.5 \text{ ns}$	t _{TLH} , t _{THL}	5.0 10 15		100 50 40	200 100 80	ns
Propagation Delay, Clock to Q (2^{8} Output) t_{PLH} , $t_{PHL} = (1.7 \text{ ns/pF}) C_{L} + 3415 \text{ ns}$ t_{PLH} , $t_{PHL} = (0.66 \text{ ns/pF}) C_{L} + 1217 \text{ ns}$ t_{PLH} , $t_{PHL} = (0.5 \text{ ns/pF}) C_{L} + 875 \text{ ns}$	t _{PLH} t _{PHL}	5.0 10 15		3.5 1.25 0.9	10.5 3.8 2.9	μs
Propagation Delay, Clock to Q (2^{16} Output) t_{PHL} , $t_{PLH} = (1.7 \text{ ns/pF}) C_L + 5915 \text{ ns}$ t_{PHL} , $t_{PLH} = (0.66 \text{ ns/pF}) C_L + 3467 \text{ ns}$ t_{PHL} , $t_{PLH} = (0.5 \text{ ns/pF}) C_L + 2475 \text{ ns}$	t _{PHL} t _{PLH}	5.0 10 15		6.0 3.5 2.5	18 10 7.5	μs
Clock Pulse Width	t _{WH(cl)}	5.0 10 15	900 300 225	300 100 85		ns
Clock Pulse Frequency (50% Duty Cycle)	f _{cl}	5.0 10 15		1.5 4.0 6.0	0.75 2.0 3.0	MHz
MR Pulse Width	t _{WH(R)}	5.0 10 15	900 300 225	300 100 85		ns
Master Reset Removal Time	t _{rem}	5.0 10 15	420 200 200	210 100 100		ns

The formulas given are for the typical characteristics only at 25°C.
 Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.



(R_{tc} AND C_{tc} OUTPUTS ARE LEFT OPEN)

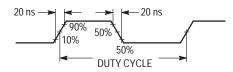
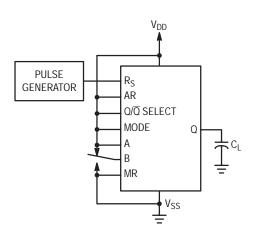


Figure 1. Power Dissipation Test Circuit and Waveform



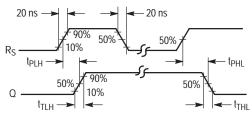
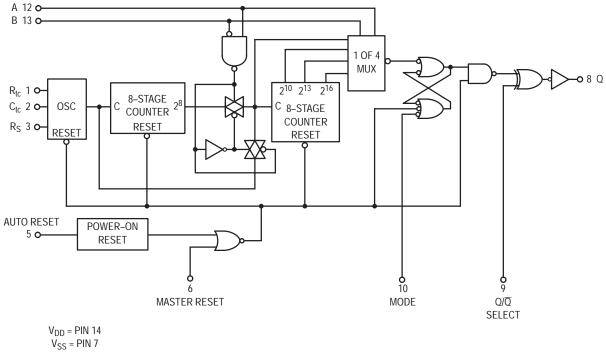


Figure 2. Switching Time Test Circuit and Waveforms

EXPANDED BLOCK DIAGRAM

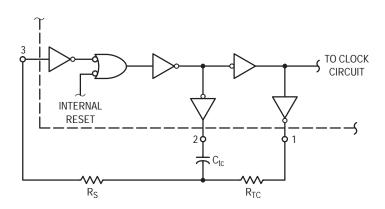


FREQUENCY SELECTION TABLE

А	В	Number of Counter Stages n	Count 2 ⁿ
0	0	13	8192
0	1	10	1024
1	0	8	256
1	1	16	65536

TRUTH TABLE

		State			
Pin		0	1		
Auto Reset,	5	Auto Reset Operating	Auto Reset Disabled		
Master Reset,	6	Timer Operational	Master Reset On		
$Q/\overline{Q},$	9	Output Initially Low After Reset	Output Initially High After Reset		
Mode,	10	Single Cycle Mode	Recycle Mode		





TYPICAL RC OSCILLATOR CHARACTERISTICS

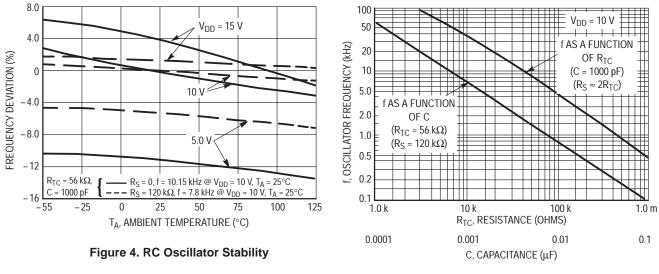


Figure 5. RC Oscillator Frequency as a Function of R_{tc} and C_{tc}

OPERATING CHARACTERISTICS

With Auto Reset pin set to a "0" the counter circuit is initialized by turning on power. Or with power already on, the counter circuit is reset when the Master Reset pin is set to a "1". Both types of reset will result in synchronously resetting all counter stages independent of counter state. Auto Reset pin when set to a "1" provides a low power operation.

The RC oscillator as shown in Figure 3 will oscillate with a frequency determined by the external RC network i.e.,

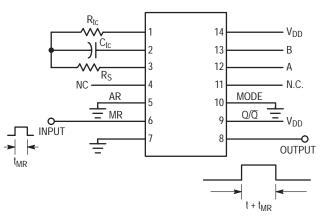
$$f = \frac{1}{2.3 R_{tc}C_{tc}} \qquad \text{if } (1 \text{ kHz} \le f \le 100 \text{ kHz})$$

and $R_S \approx 2 R_{tc}$ where $R_S \ge 10 \ k\Omega$

The time select inputs (A and B) provide a two-bit address to output any one of four counter stages $(2^8, 2^{10}, 2^{13} \text{ and} 2^{16})$. The 2^n counts as shown in the Frequency Selection Table represents the Q output of the Nth stage of the counter. When A is "1", 2^{16} is selected for both states of B. However, when B is "0", normal counting is interrupted and the 9th counter stage receives its clock directly from the oscillator (i.e., effectively outputting 2^8).

The Q/\overline{Q} select output control pin provides for a choice of output level. When the counter is in a reset condition and Q/\overline{Q} select pin is set to a "0" the Q output is a "0", correspondingly when Q/\overline{Q} select pin is set to a "1" the Q output is a "1".

When the mode control pin is set to a "1", the selected count is continually transmitted to the output. But, with mode pin "0" and after a reset condition the R_S flip–flop (see Expanded Block Diagram) resets, counting commences, and after 2^{n-1} counts the R_S flip–flop sets which causes the output to change state. Hence, after another 2^{n-1} counts the applied or a change in the mode pin level is required to reset the single cycle operation.



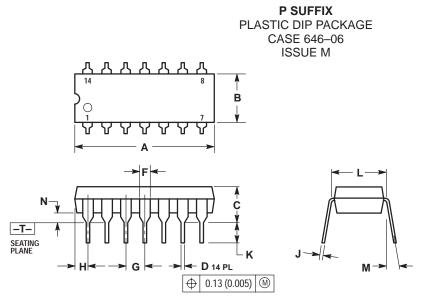
DIGITAL TIMER APPLICATION

When Master Reset (MR) receives a positive pulse, the internal counters and latch are reset. The Q output goes high and remains high until the selected (via A and B) number of clock pulses are counted, the Q output then goes low and remains low until another input pulse is received.

This "one shot" is fully retriggerable and as accurate as the input frequency. An external clock can be used (pin 3 is the clock input, pins 1 and 2 are outputs) if additional accuracy is needed.

Notice that a setup time equal to the desired pulse width output is required immediately following initial power up, during which time Q output will be high.

PACKAGE DIMENSIONS



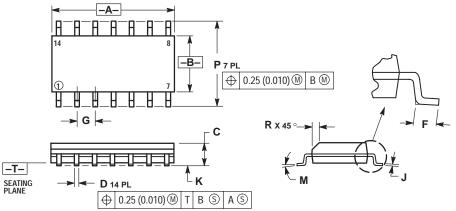
NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
 DIMENSION B DOES NOT INCLUDE MOLD FLASH.

5. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.715	0.770	18.16	18.80	
В	0.240	0.260	6.10	6.60	
С	0.145	0.185	3.69	4.69	
D	0.015	0.021	0.38	0.53	
F	0.040	0.070	1.02	1.78	
G	0.100	BSC	2.54 BSC		
Н	0.052	0.095	1.32	2.41	
J	0.008	0.015	0.20	0.38	
К	0.115	0.135	2.92	3.43	
L	0.290	0.310	7.37	7.87	
Μ		10°		10°	
Ν	0.015	0.039	0.38	1.01	

D SUFFIX PLASTIC SOIC PACKAGE CASE 751A-03 **ISSUE F**



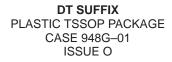
NOTES:

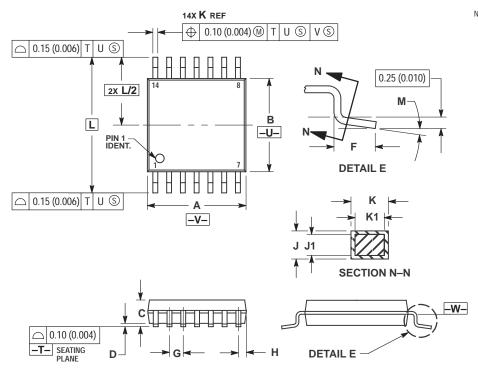
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

- Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
 5. DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	8.55	8.75	0.337	0.344	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.054	0.068	
D	0.35	0.49	0.014	0.019	
F	0.40	1.25	0.016	0.049	
G	1.27	BSC	0.050 BSC		
J	0.19	0.25	0.008	0.009	
К	0.10	0.25	0.004	0.009	
М	0 °	7°	0 °	7°	
Р	5.80	6.20	0.228	0.244	
R	0.25	0.50	0.010	0.019	

PACKAGE DIMENSIONS





NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

2. 3.

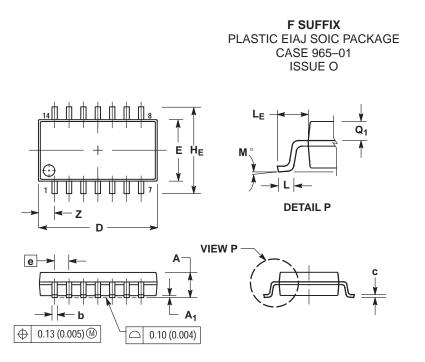
Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER. 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE. 4. DIMENSION B DOES NOT INCLUDE

INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT

INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE. 5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION. 6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY. 7. DIMENSION A AND B ARE TO BE IDETERMINED AT DATUM PLANE-W-

DETE		nt datur Neters	IPLANE · INC	-₩ HES	
DIM	MIN	MAX	MIN	MAX	
Α	4.90	5.10	0.193	0.200	
В	4.30	4.50	0.169	0.177	
С		1.20		0.047	
D	0.05	0.15	0.002	0.006	
F	0.50	0.75	0.020	0.030	
G	0.65	BSC	0.026 BSC		
Н	0.50	0.60	0.020	0.024	
J	0.09	0.20	0.004	0.008	
J1	0.09	0.16	0.004	0.006	
Κ	0.19	0.30	0.007	0.012	
K1	0.19	0.25	0.007	0.010	
L	6.40 BSC		0.252	BSC	
М	0 °	8°	0°	8 °	

PACKAGE DIMENSIONS



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI V14 5M 1982

2. CONTROLLING DIMENSION: MILLIMETER.

 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15

(0.006) PER SIDE. 4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.

REFERENCE ONLY. 5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α		2.05		0.081
A ₁	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
С	0.18	0.27	0.007	0.011
D	9.90	10.50	0.390	0.413
Ε	5.10	5.45	0.201	0.215
е	1.27 BSC		0.050 BSC	
HE	7.40	8.20	0.291	0.323
0.50	0.50	0.85	0.020	0.033
LE	1.10	1.50	0.043	0.059
Μ	0 °	10 °	0 °	10 °
Q ₁	0.70	0.90	0.028	0.035
Ζ		1.42		0.056

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